09/15/2005 THU 10:15 FAX 949 282 1002 FARJAMI & FARJAMI LLP →++ USPTO

**2**002/010

Attorney Docket No.: 0180154

## IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

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Art Unit: 2814

SEP 1 5 2005

Examiner: Pham, Long

In re Application of: Jeon, et al.

Serial No.: 10/761,009

Filed: 01/20/2004

For: Method for Forming a Thin, High Quality Buffer Layer in a Field Effect Transistor and Related Structure

## **AMENDMENT AND RESPONSE TO FINAL OFFICE ACTION**

Mail Stop AF
Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

## Dear Sir/Madam:

This is in response to the Final Office Action dated July 26, 2005 in the abovereferenced patent application. Please enter and consider the following amendments and remarks.